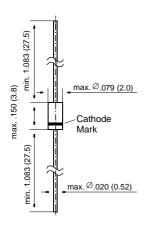
BAV19 THRU BAV21

Small Signal Diodes

DO-35



Dimensions in inches and (millimeters)

FEATURES

- Silicon Epitaxial Planar Diodes
- For general purpose
- ◆ These diodes are also available in other case styles including: the SOD-123 case with the type designation BAV19W BAV21W, the MiniMELF case with the type designation BAV101 BAV103, and the SOT-23 case with the type designation BAS19 BAS21.

MECHANICAL DATA

Case: DO-35 Glass Case Weight: approx. 0.13 g

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified

		Symbol	Value	Unit
Reverse Voltage	BAV19 BAV20 BAV21	V _R V _R V _R	120 200 250	V V V
Forward DC Current at T _{amb} = 25 °C		IF	250 ¹⁾	mA
Rectified Current (Average) Half Wave Rectification with Resist. Load at T_{amb} = 25 °C and f \geq 50 Hz		I ₀	2001)	mA
Repetitive Peak Forward Current at f \geq 50 Hz, Θ = 180 $^{\circ}$, T_{amb} = 25 $^{\circ}$ C		I _{FRM}	625 ¹⁾	mA
Surge Forward Current at t < 1 s, T _j = 25 °C		I _{FSM}	1	Α
Power Dissipation at T _{amb} = 25 °C		P _{tot}	5001)	mW
Junction Temperature		T _j	175 ¹⁾	°C
Storage Temperature Range		T _S	-65 to +175 ¹⁾	°C

1) Valid provided that leads are kept at ambient temperature at a distance of 8 mm from case



BAV19 THRU BAV21

ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified

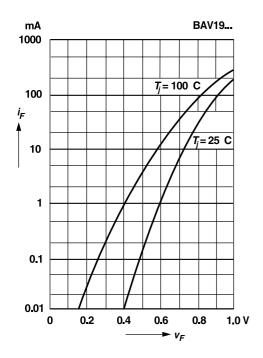
	Symbol	Min.	Тур.	Max.	Unit
Forward voltage at I _F = 100 mA	V _F	_	_	1	V
	19 I _R 20 I _R 20 I _R 21 I _R	- - - - -	- - - - -	100 15 100 15 100 15	nA μA nA μA nA
Dynamic Forward Resistance at I _F = 10 mA	r _f	-	5	-	Ω
Capacitance at V _R = 0, f = 1 MHz	C _{tot}	_	1.5	-	pF
Reverse Recovery Time from I_F = 30 mA through I_R = 30 mA to I_R = 3 mA; R_L = 100 Ω	t _{rr}	_	-	50	ns
Thermal Resistance Junction to Ambient Air	R _{thJA}	_	-	3751) 2)	K/W

¹⁾ Valid provided that leads are kept at ambient temperature at a distance of 8 mm from case



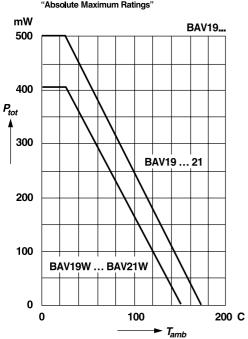
RATINGS AND CHARACTERISTIC CURVES BAV19 THRU BAV21

Forward characteristics



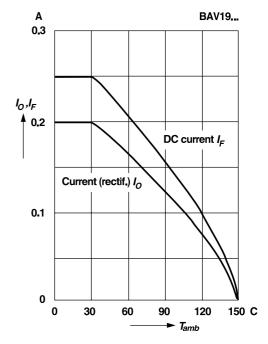
Admissible power dissipation versus ambient temperature

For conditions, see footnote in table "Absolute Maximum Ratings"

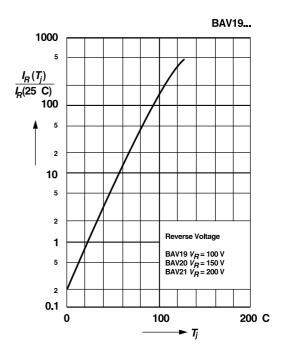


Admissible forward current versus ambient temperature

For conditions, see footnote in table "Absolute Maximum Ratings"



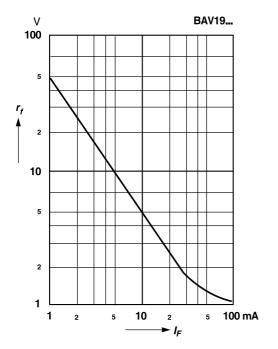
Leakage current versus junction temperature





RATINGS AND CHARACTERISTIC CURVES BAV19 THRU BAV21

Dynamic forward resistance versus forward current



Capacitance versus reverse voltage

